

6-ch. phototransistor array 0.68mm optical pitch on plastic SMD package

General Description

OIT25C consists in a six single diced silicon phototransistor. The phototransistors have a common collector on the back substrate, which is tied to a single pad and every emitter is accessible to specific pad. The optical pitch of the array is 0.68 mm (available also on 0.60 mm), the LCC package electrical pitch is 1.27 mm. The active area of each element is 0.20 x 0.45 mm².

The advantages of this product are the high uniformity of the silicon sensors, due to the monolithic construction and to the extremely controlled microelectronic process, the high stability of the signal and the high optical responsivity, due to the antireflective coating deposited on the phototransistor's areas.

The encapsulant is a clear silicone material, having medium hardness, in order to be robust against RoHS soldering processes and high optical performances (transmittance close to 100% in the range 300-900nm).

Two reference marks are available for the precise collimator positioning.

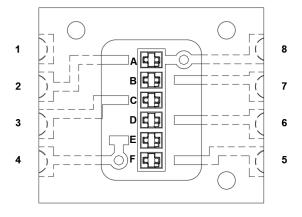
Applications

Optical encoders

Incremental encoders

Optical Receivers

Controls/drives



TOP VIEW



Features

- High uniformity of silicon cells
- High temperature range
- High transparency resin
- High gain
- Designed to meet industrial specifications
- Reference holes for precise mounting
- Reference dots for very precise mounting

Pin Functions

No.	Name	Function
1	N.C.	Not connected
2	ΑE	Phototransistor A Emitter
3	CE	Phototransistor C Emitter
4	EC	Phototransistor E Emitter
5	FE	Phototransistor F Emitter
6	DE	Phototransistor D Emitter
7	BE	Phototransistor B Emitter
8	CC	Common collector

Ordering information

OIT25C

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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Min	Max	Unit
T _A	Operating Temperature Range	-40	100	°C
Ts	Storage Temperature	-40	100	°C
T _{Sol}	Lead Temperature (solder) 3s		230	°C
$V_{R(BR)}$	Breakdown Voltage Collector-Emitter @ T _A =25°C I _B =100nA I _C =1mA	50		V
P _D	Power Dissipation @ T _A =25°C		150	mW
ESDS	Electrostatic Discharge Susceptibility (Human Body Model, ESCC20800)		3	class

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _D	Dark Current	V _R =10V		5	100	nA
R_{λ}	Responsivity	V _{CE} =5V λ=880nm	0.5			A/W
λ_{P}	Peak Responsivity	V _{CE} =5V		750		nm
Δλ	Spectral Bandwidth @ 50%	V _{CE} =5V	500		950	nm
I _{ec0}	Emitter-Collector Current	V _{CE} =7.7V		0.1	100	μA
I _{ce0}	Collector-Emitter Current	V _{CE} =52V		0.1	100	μA
H _{FE}	Gain	V _{CC} =5V I _C =2mA	500	1100	2000	
V _{CE(sat)}	Saturation Voltage	I _E =2mA I _B =20μA		80	200	mV
I _{C(on)}	On-state Collector Current	V _{CE} =5V E _E =1.0mW/cm ²		1		mA

AC SWITCHING CHARACTERISTICS

 $T_A = 25$ °C unless otherwise noted.

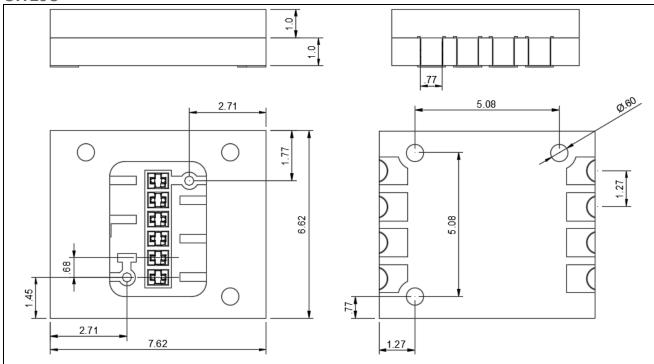
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _R	Rise Time	V_{CC} =5 V I_{C} =1 mA R_{1} =1 $k\Omega$		10		μs
t _F	Fall Time	V_{CC} =5 $V I_{C}$ =1 $mA R_{1}$ =1 $k\Omega$		11		μs

MECHANICAL CHARACTERISTICS

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Α	Phototransistor Active Area			0.09		mm²
L	Length of the Active Area			0.2		mm
W	Width of the Active Area			0.45		mm



OIT25C



Units=mm Mechanical tolerance=+/-0.2mm Die positioning tolerance=±0.050mm

PACKAGE CHARACTERISTICS

Symbol	Parameter	Value	Unit
S _F	Pad Surface Finishing	GOLD	
SL	Pad Shelf Life	6	months
MSL	Moisture Sensitive Level ‡ (see note at bottom page)	3	Level

TYPICAL PERFORMANCE CURVES

Figure 1 – Output voltage Vs Temperature

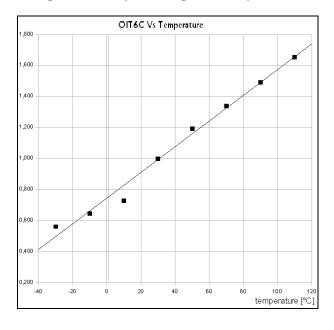
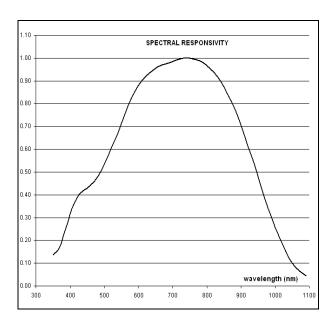


Figure 2 – Normalized spectral responsitivity



[‡] According to Jedec standard J-STD-020D.1



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